## Seong Ho Han

List of Publications by Year in descending order

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SEONC HO HAN

#	Article	IF	CITATIONS
1	Novel Heteroleptic Tin(II) Complexes Capable of Forming SnO and SnO <sub>2</sub> Thin Films Depending on Conditions Using Chemical Solution Deposition. ACS Omega, 2022, 7, 1232-1243.	3.5	6
2	Synthesis of Heteroleptic Zinc Complexes Containing Aminoalkoxide and β â€Điketonate Ligands. ChemistrySelect, 2021, 6, 5880-5884.	1.5	1
3	Synthesis of New Heteroleptic Indium Complexes as Potential Precursors for Indium Oxide Thin Films. European Journal of Inorganic Chemistry, 2021, 2021, 2480-2485.	2.0	2
4	Group IV Transition Metal (M = Zr, Hf) Precursors for High-Î⁰ Metal Oxide Thin Films. Inorganic Chemistry, 2021, 60, 17722-17732.	4.0	4
5	Synthesis and characterization of novel zinc precursors for ZnO thin film deposition by atomic layer deposition. Dalton Transactions, 2020, 49, 4306-4314.	3.3	6
6	Synthesis and Structure of Tin and Germanium Complexes as Precursors Containing Alkoxyaminoalkoxide Ligands for Thin Film Transistors. European Journal of Inorganic Chemistry, 2020, 2020, 2074-2079.	2.0	1
7	Synthesis of Indium Complexes for Thin Film Transistor Applications Bearing N â€Alkoxy Carboxamide Ligands. ChemistrySelect, 2018, 3, 6691-6695.	1.5	5
8	Synthesis and Structure of Novel Tin Complexes Containing Aminoalkoxide Ligands. ChemistrySelect, 2018, 3, 7836-7839.	1.5	2
9	Germanium Compounds Containing Geâ•E Double Bonds (E = S, Se, Te) as Single-Source Precursors for Germanium Chalcogenide Materials. Inorganic Chemistry, 2017, 56, 4084-4092.	4.0	19
10	New Heteroleptic Cobalt Precursors for Deposition of Cobalt-Based Thin Films. ACS Omega, 2017, 2, 5486-5493.	3.5	7
11	Synthesis of novel tin complexes using functionalized oxime ligands. Inorganica Chimica Acta, 2016, 446, 1-5.	2.4	3